imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Preferred Device

Sensitive Gate Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Annular PNPN devices designed for high volume consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits. Supplied in an inexpensive plastic TO-92/TO-226AA package which is readily adaptable for use in automatic insertion equipment.

Features

- Sensitive Gate Trigger Current 200 µA Maximum
- Low Reverse and Forward Blocking Current 50 μA Maximum, T_C = 110°C
- Low Holding Current 5 mA Maximum
- Passivated Surface for Reliability and Uniformity
- Device Marking: Device Type, e.g., 2N5060, Date Code
- Pb-Free Packages are Available*



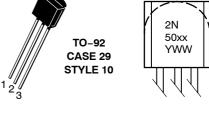
ON Semiconductor®

http://onsemi.com

SILICON CONTROLLED RECTIFIERS 0.8 A RMS, 30 – 200 V







50xx Specific Device Code Y = Year WW = Work Week

PIN ASSIGNMENT			
1 Cathode			
2	Gate		
3	Anode		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
$\begin{array}{l} \mbox{Peak Repetitive Off-State Voltage (Note 1)} \\ (T_J = -40 \mbox{ to } 110^{\circ}\mbox{C}, \mbox{ Sine Wave}, \\ 50 \mbox{ to } 60 \mbox{ Hz}, \mbox{ R}_{GK} = 1 \mbox$	V _{DRM,} V _{RRM}	30 60 100 200	V
On-State Current RMS (180° Conduction Angles; $T_C = 80^{\circ}C$)	I _{T(RMS)}	0.8	Α
*Average On-State Current (180° Conduction Angles) ($T_C = 67^{\circ}C$) ($T_C = 102^{\circ}C$)	I _{T(AV)}	0.51 0.255	A
*Peak Non-repetitive Surge Current, T _A = 25°C (1/2 cycle, Sine Wave, 60 Hz)	I _{TSM}	10	A
Circuit Fusing Considerations (t = 8.3 ms)	l ² t	0.4	A ² s
*Average On-State Current (180° Conduction Angles) ($T_c = 67^{\circ}C$) ($T_c = 102^{\circ}C$)	I _{T (AV)}	0.51 0.255	A
*Forward Peak Gate Power (Pulse Width $\leq 1.0 \mu sec; T_A = 25^{\circ}C)$	P _{GM}	0.1	W
*Forward Average Gate Power (T _A = 25°C, t = 8.3 ms)	P _{G(AV)}	0.01	W
*Forward Peak Gate Current (Pulse Width $\leq 1.0 \ \mu sec; T_A = 25^{\circ}C$)	I _{GM}	1.0	А
*Reverse Peak Gate Voltage (Pulse Width $\leq 1.0 \ \mu sec; T_A = 25^{\circ}C$)	V _{RGM}	5.0	V
*Operating Junction Temperature Range	TJ	-40 to +110	°C
*Storage Temperature Range	T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic		Мах	Unit
*Thermal Resistance, Junction-to-Case (Note 2)	$R_{\theta JC}$	75	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W

2. This measurement is made with the case mounted "flat side down" on a heatsink and held in position by means of a metal clamp over the curved surface.

*Indicates JEDEC Registered Data.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

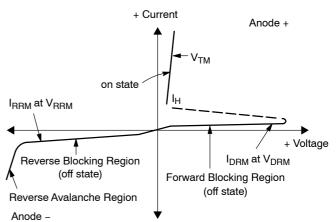
Characteristic		Symbol	Min	Тур	Max	Uni
OFF CHARACTERISTICS						
*Peak Repetitive Forward or Reverse Blocking Currer (V_{AK} = Rated V_{DRM} or V_{RRM})	nt (Note 3) T _C = 25°C T _C = 110°C	I _{DRM} , I _{RRM}	-	-	10 50	μΑ μΑ
ON CHARACTERISTICS						
*Peak Forward On-State Voltage (Note 4) (I _{TM} = 1.2 A peak @ T _A = 25°C)		V _{TM}	-	-	1.7	V
Gate Trigger Current (Continuous DC) (Note 5) *(V _{AK} = 7.0 Vdc, R_L = 100 Ω)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$	I _{GT}		-	200 350	μΑ
Gate Trigger Voltage (Continuous DC) (Note 5) *(V _{AK} = 7.0 Vdc, R _L = 100 Ω)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$	V _{GT}	-	-	0.8 1.2	V
*Gate Non-Trigger Voltage (V_{AK} = Rated V_{DRM} , R_L = 100 Ω) T_C = 110°C		V _{GD}	0.1	-	-	V
Holding Current (Note 3) *(V _{AK} = 7.0 Vdc, initiating current = 20 mA)	$T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$	Ι _Η			5.0 10	mA
Turn-On Time Delay Time Rise Time (I _{GT} = 1.0 mA, V _D = Rated V _{DRM} , Forward Current = 1.0 A, di/dt = 6.0 A/μs		t _d t _r		3.0 0.2	-	μs
Turn-Off Time (Forward Current = 1.0 A pulse, Pulse Width = 50 μs, 0.1% Duty Cycle, di/dt = 6.0 A/μs,		tq				μs
$dv/dt = 20 V/\mu s$, $I_{GT} = 1 mA$) 2N5060, 2N 2N5062, 2N				10 30	-	

Critical Rate of Rise of Off-State Voltage	dv/dt	-	30	-	V/μs
(Rated V _{DRM} , Exponential, R_{GK} = 1 k Ω)					

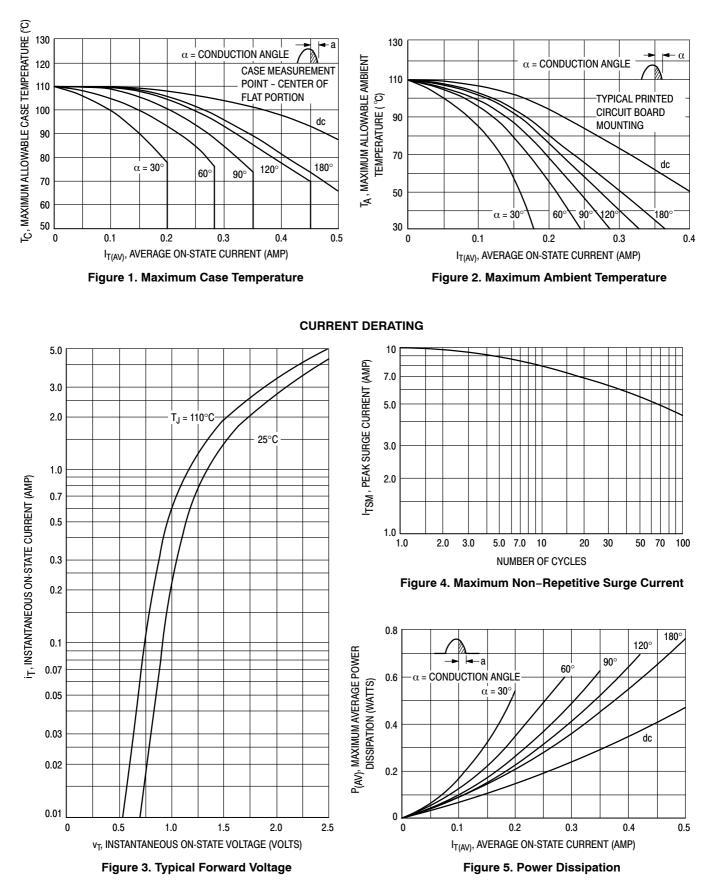
R_{GK} = 1000 Ω is included in measurement.
Forward current applied for 1 ms maximum duration, duty cycle ≤ 1%.
R_{GK} current is not included in measurement.
*Indicates JEDEC Registered Data.

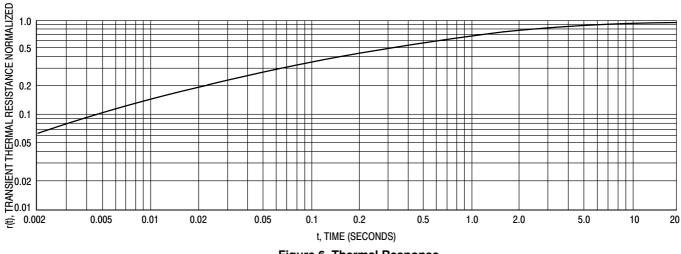
Voltage Current Characteristic of SCR

Symbol	Parameter
V _{DRM}	Peak Repetitive Off State Forward Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak on State Voltage
Ι _Η	Holding Current



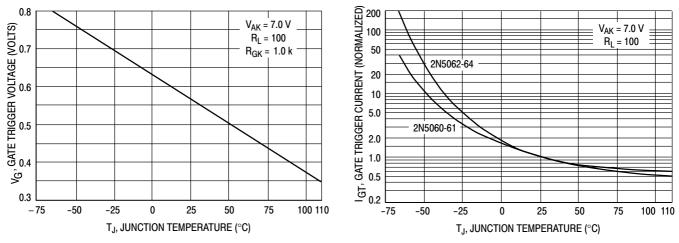
CURRENT DERATING





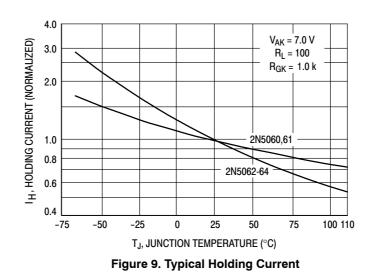


TYPICAL CHARACTERISTICS









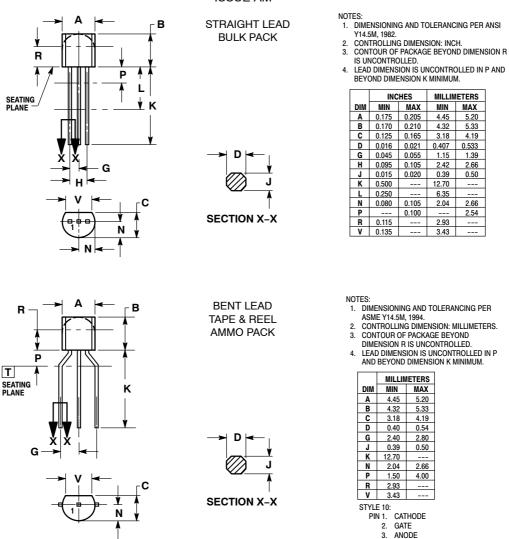
ORDERING INFORMATION

Device	Package	Shipping [†]
2N5060	TO-92	5,000 Units / Box
2N5060G	TO-92 (Pb-Free)	5,000 Units / Box
2N5060RLRA	TO-92	2,000 / Tape & Reel
2N5060RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel
2N5060RLRM	TO-92	2,000 / Ammo Pack
2N5060RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
2N5061	TO-92	5,000 Units / Box
2N5061G	TO-92 (Pb-Free)	5,000 Units / Box
2N5061RLRA	TO-92	2,000 / Tape & Reel
2N5061RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel
2N5062	TO-92	5,000 Units / Box
2N5062G	TO-92 (Pb-Free)	5,000 Units / Box
2N5062RLRA	TO-92	2,000 / Tape & Reel
2N5062RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel
2N5064	TO-92	5,000 Units / Box
2N5064RLRA	TO-92	2,000 / Tape & Reel
2N5064RLRM	TO-92	2,000 / Ammo Pack
2N5064RLRMG	TO-92 (Pb-Free)	2,000 / Ammo Pack
2N5064RLRAG	TO–92 (Pb–Free)	2000 / Tape & Reel
2N5064G	TO-92 (Pb-Free)	5000 Units / Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**



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